



## scintillating active Transverse Energy Filter

a novel detector concept for low-energy electron background discrimination

speaker: Joscha Lauer (Institute for Astroparticle Physics (IAP), KIT) for the KATRIN Collaboration

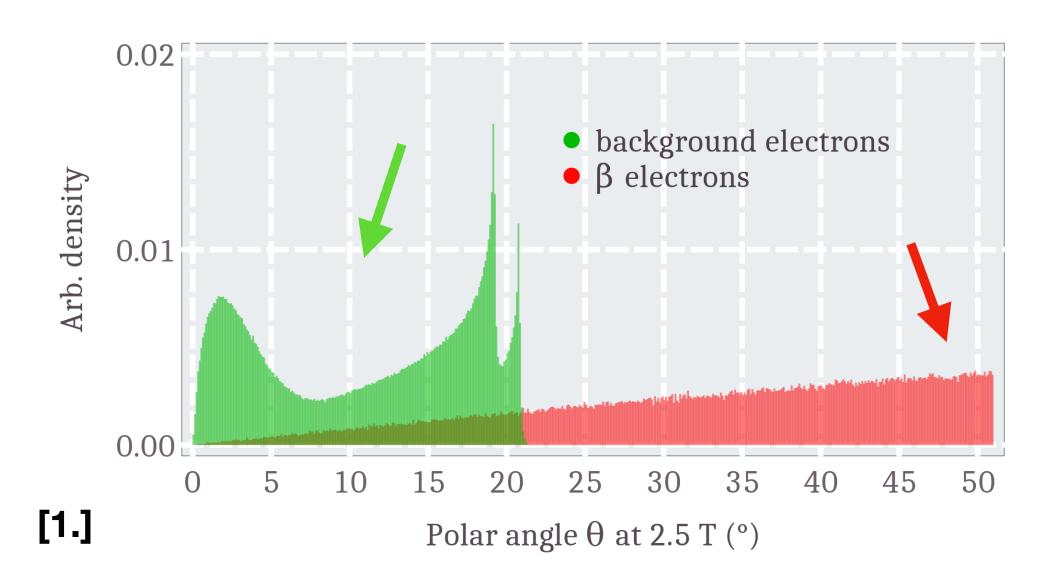
## Transverse Energy Filter (TEF)

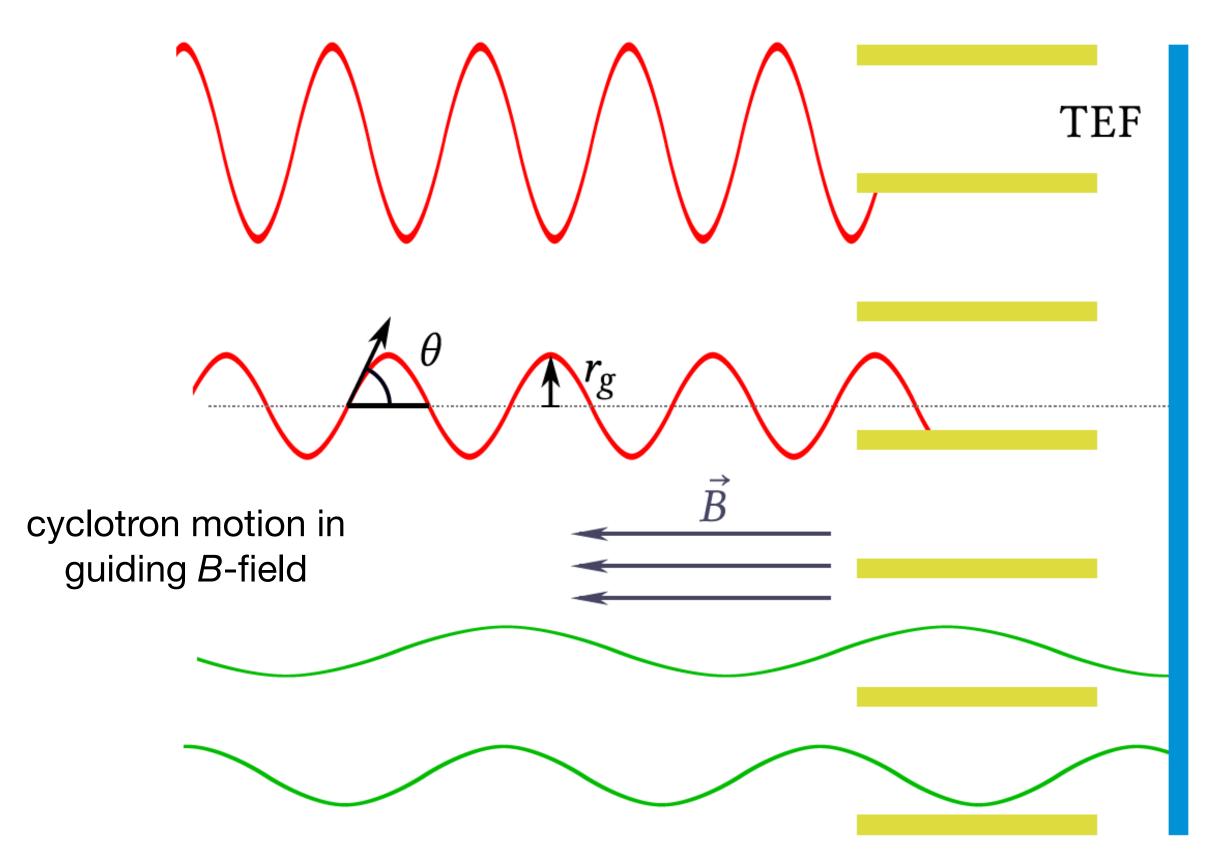
#### the TEF principle

 $E_T = E \sin^2(\theta)$ 



- background electrons
- tritium β electrons
- detector: active TEF = "aTEF fraction"
- background discrimination for tritium
   β spectroscopy with KATRIN





KATRIN: low energy (origin) ↔ low angles (detector)

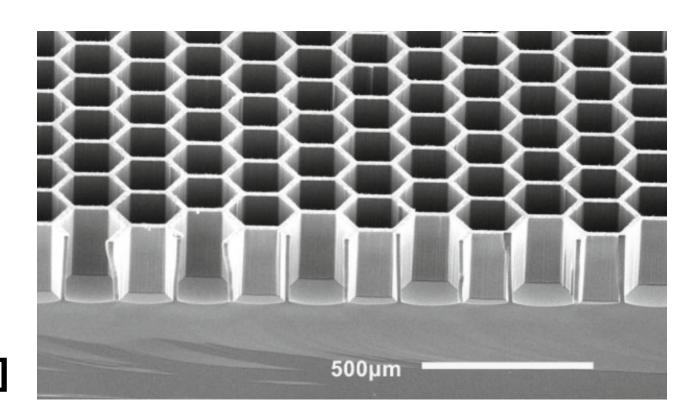
## detector concept: active TEF (aTEF)

#### two different approaches by

Si-aTEF

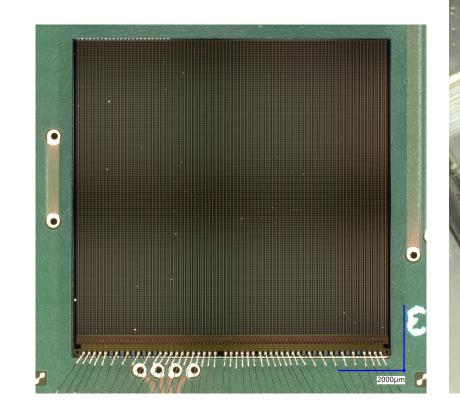
Eur. Phys. J. C 82, 922 (2022) [2.]

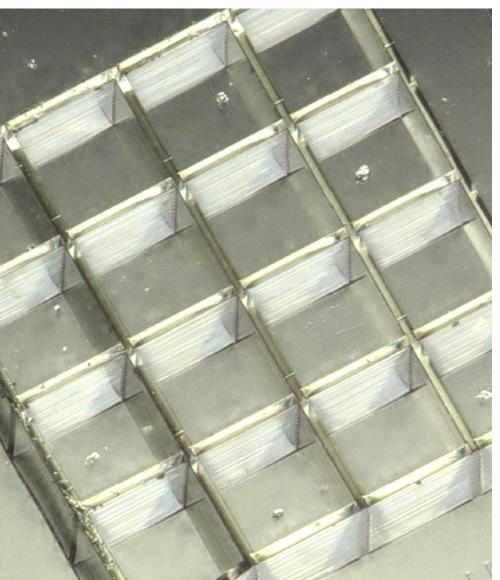
- silicon-based aTEF detector
- etched Si-PIN diodes
- **T 123.6**, tomorrow at 17:05
- **HK 74.28**, tomorrow at 17:30
- **T 143.5**, tomorrow at 18:30



#### scint-aTEF

- scintillator-based aTEF detector
- scintillator grid and single-photon detector
- **T 74.2**, today at 16:05
- **T 74.3**, today at 16:20
- **T 74.4**, today at 16:35





[3.]

[2.]

scintillator-based aTEF

the scintillating approach

4 "layers":

non-scintillating top

scintillator grid

non-scintillating base plate

single-photon detector

scint-aTEF

1. incident single low-energy (~18.6keV) electron

**2.** if  $\theta/r_g$  sufficiently large: multiple scintillation photons

3. photon footprint on detector

#### scintillator

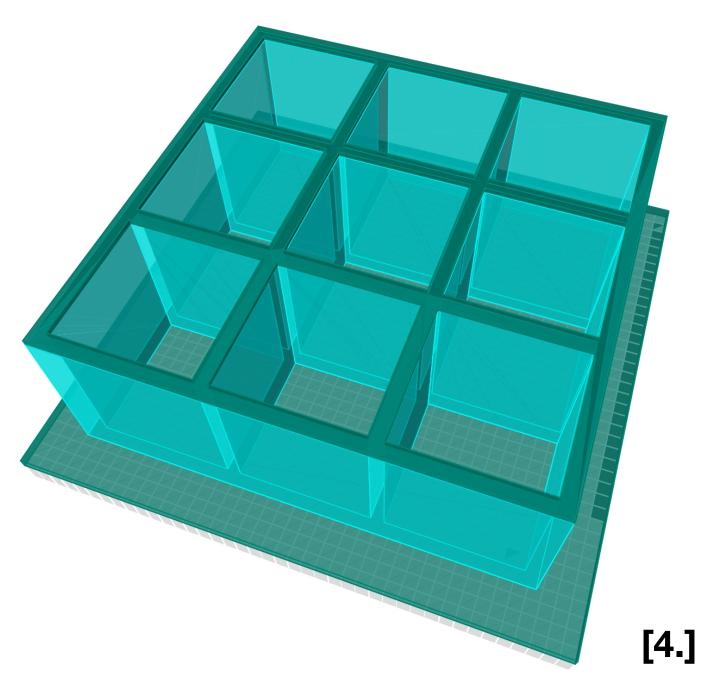
#### 3d-microstructured plastic grid

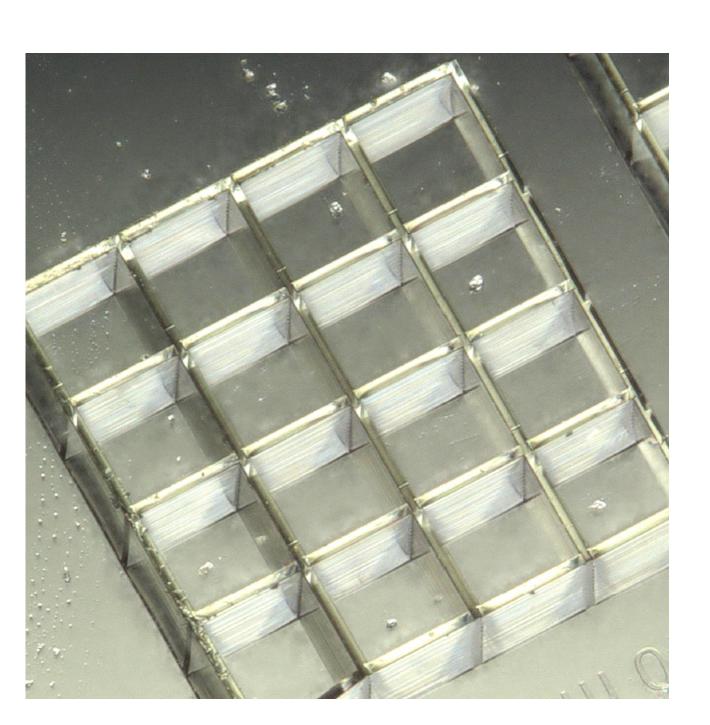
- plastic scintillator: low  $Z \rightarrow$  low backscattering
- non-scint. low Z top/bottom: e.g. PMMA
- quadratic 3d grid dimensions:
  - cells of  $\sim 250 \times 250 \, \mu m^2$ ,  $\sim 25 \, \mu m$  walls
  - until now ~300 µm height
- → geometry optimizations using Geant4 are ongoing

T 74.3, today at 16:20

diameter: gomm o(105) grid cells

[3.]
KATRIN Focal
Plane Detector

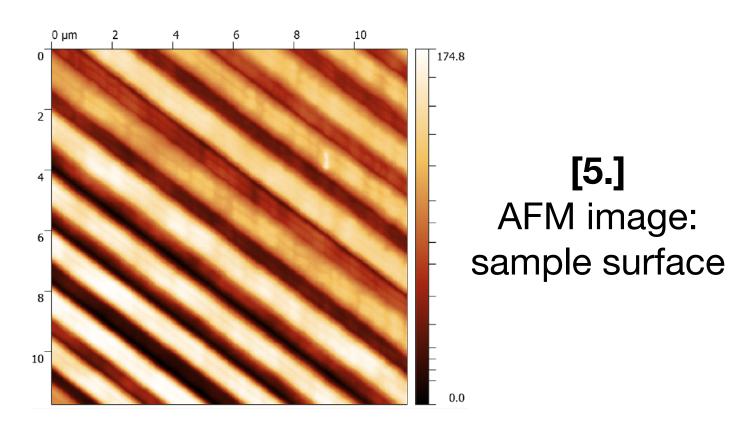


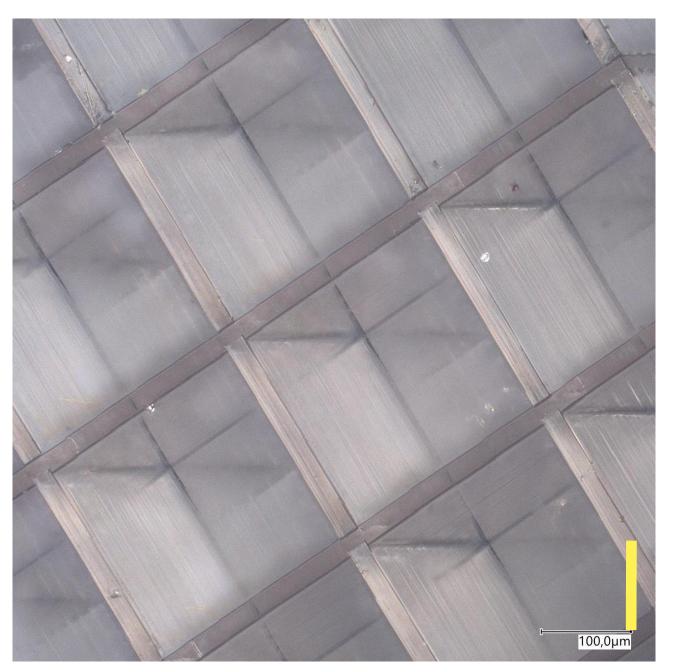


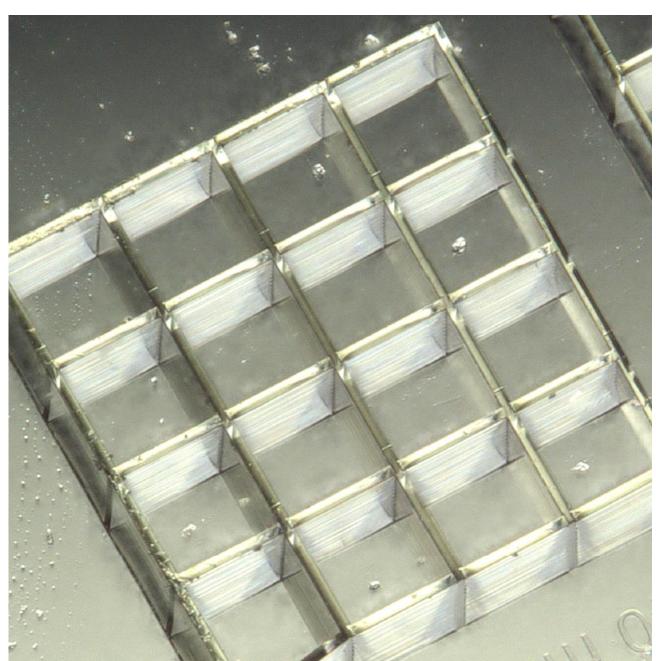
#### scintillator

#### 3d-microstructured plastic grid

- manufacturing by 2-Photon Polymerization (2PP)
- R&D: suitable resin for 2PP of plastic scintillator & printing strategies
- important aspects: T 74.4, today at 16:35
  - surface properties ( $\sigma_a < 5^\circ$ )
  - light yield (max. ~10 γ/keV deposit)
  - emission spectrum



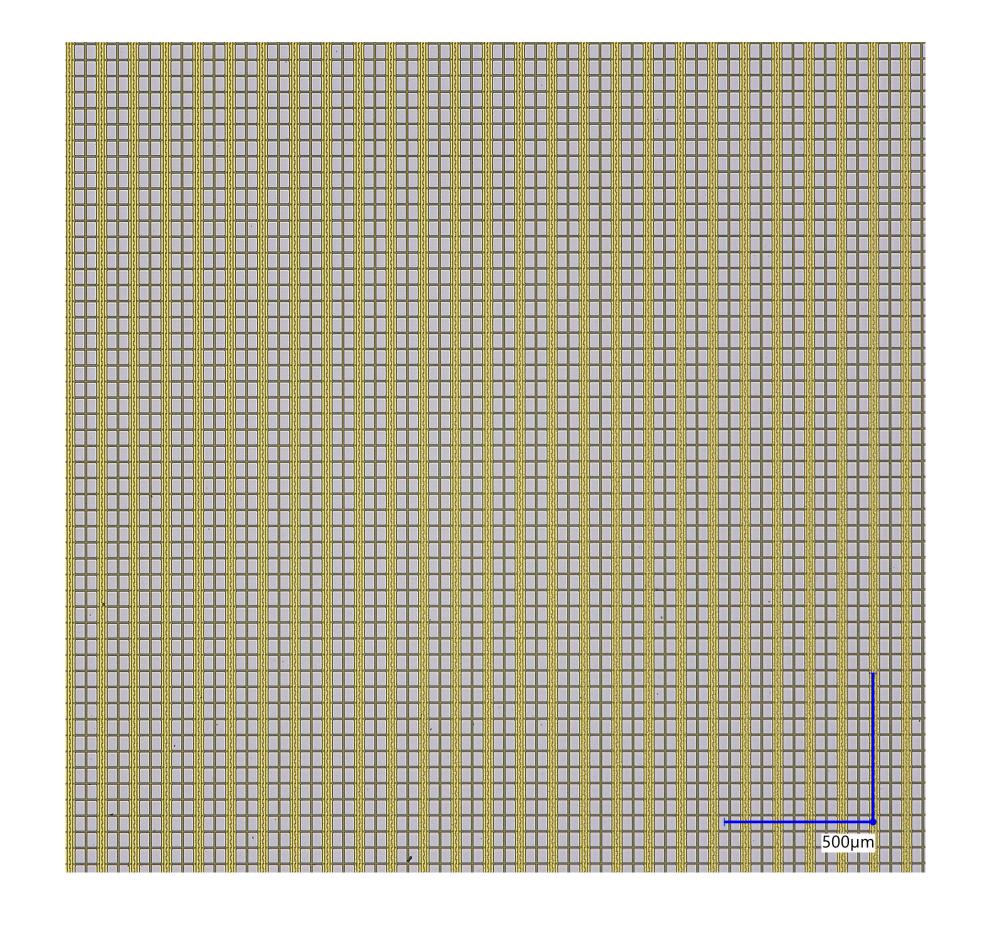




[4.]

# **detector CMOS-SPAD-based single photon detection**

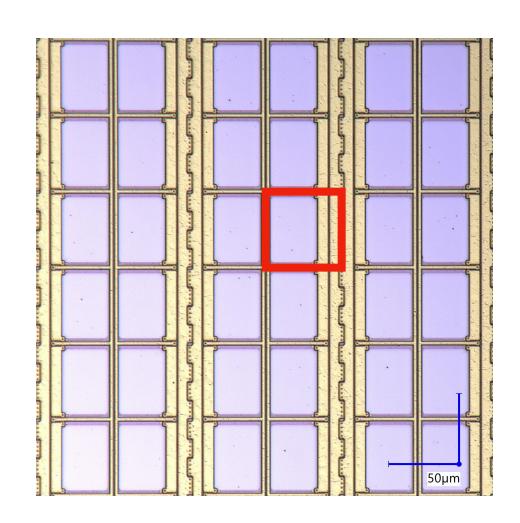
- Single-Photon Avalanche Diode (SPAD) array
- operation above breakdown voltage  $V_{\rm BD}$  in GEIGER mode
- triggered avalanche only creates small fast external signal
- → combination with CMOS (Complementary Metal-Oxide-Semiconductor) technology → "digital SiPM"
- single noisy SPAD impairs whole array → hot SPADs can be disengaged in real time

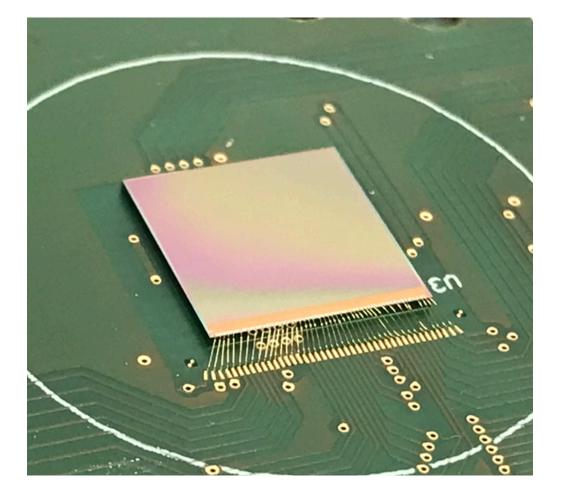


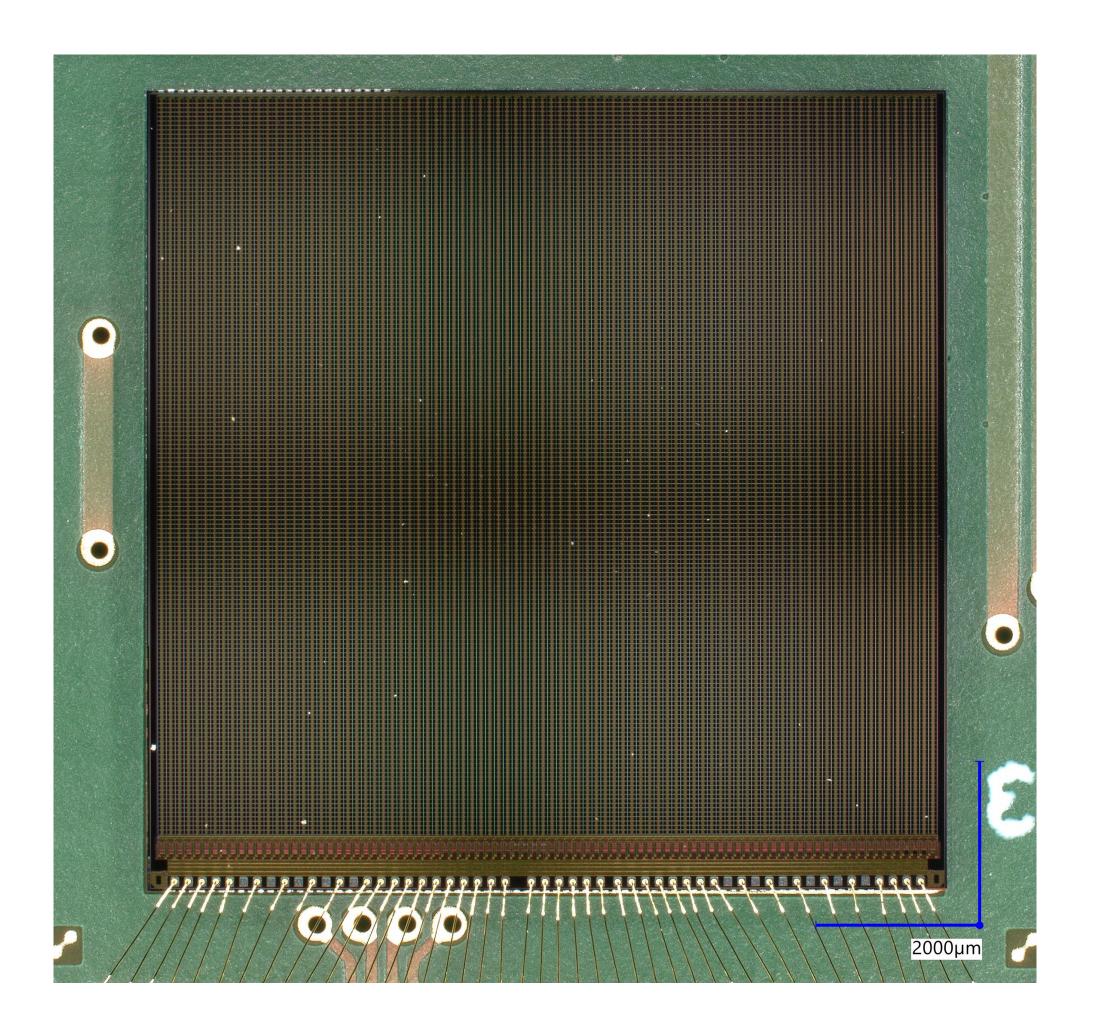
#### detector

#### Interpolating Digital Photosensor 4 (IDP4, by ZITI in Heidelberg)

- *IDP4*: CMOS-SPAD-based photodetector developed at ZITI (Uni Heidelberg) [6.]
- $9.7 \times 9.7 \,\text{mm}^2 \,(176 \times 166 = 29.2 \,\text{k SPADs})$
- 52% fill factor (active area)
- pixel:  $54 \times 54 \mu m^2$

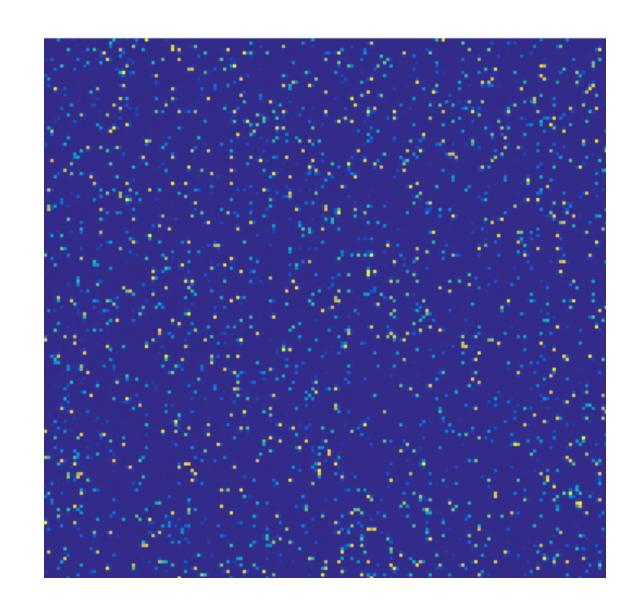




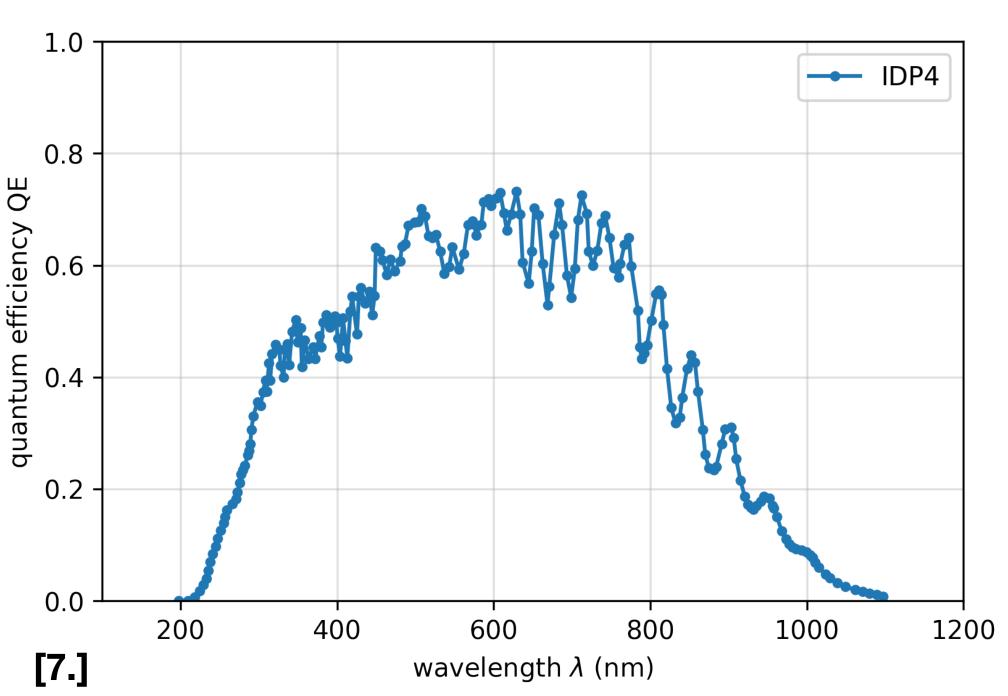


# detector CMOS-SPAD-based IDP4

- single-photon detection with O(10ns) scale time resolution
- spatial information (pixel size):
  - reconstruction of local events
  - discrimination from noise
- binary (I/O) serial array readout
- low noise achievable

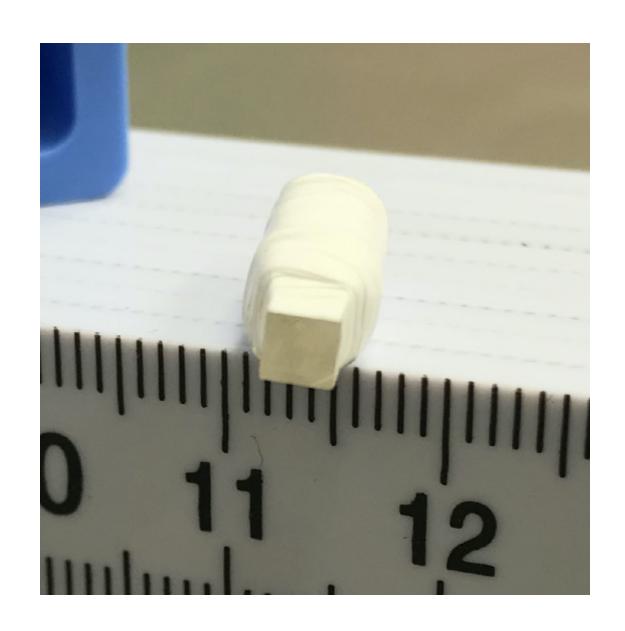


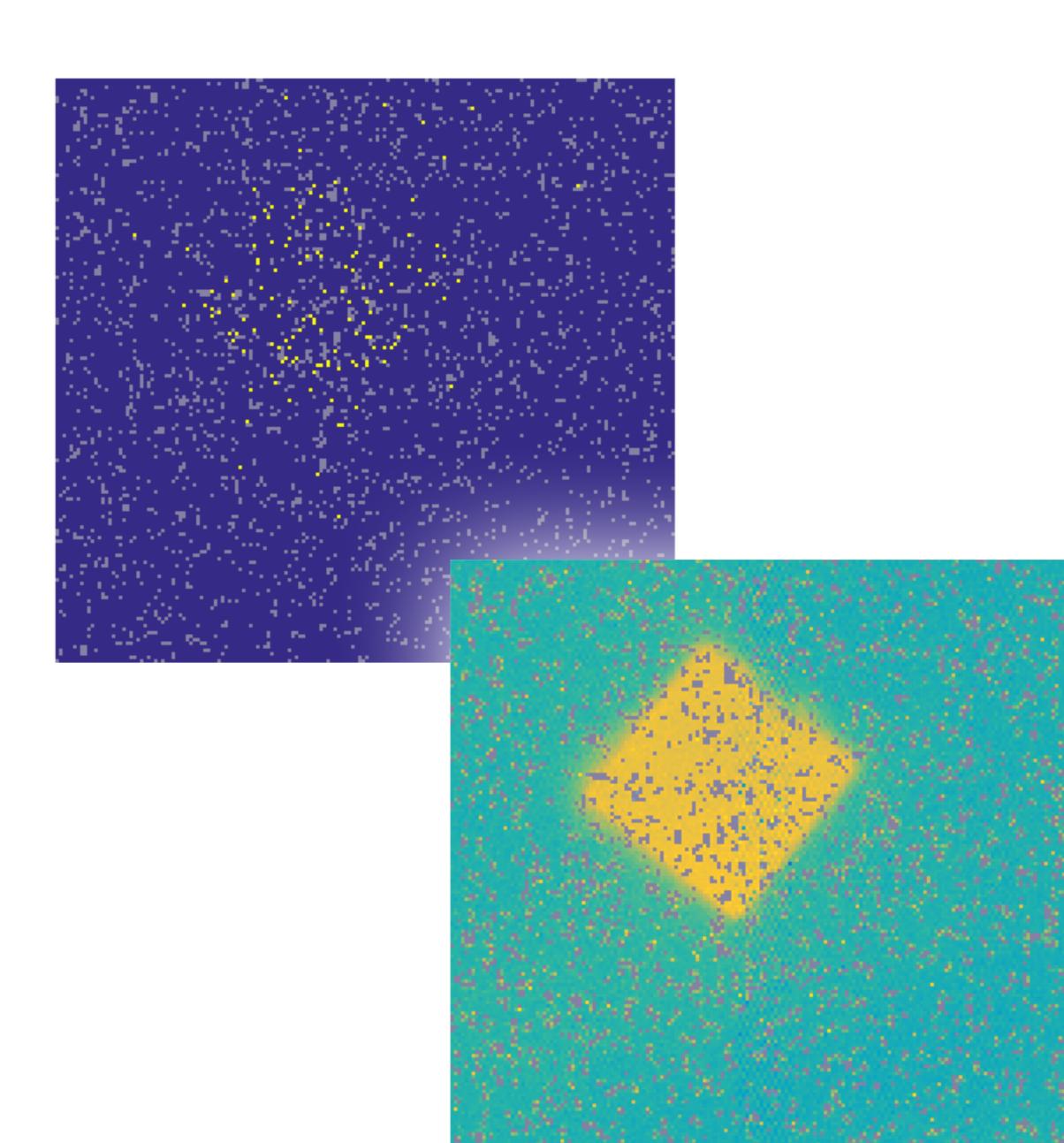
accumulated noise of hot SPADs



# photon detection imaging scintillation events

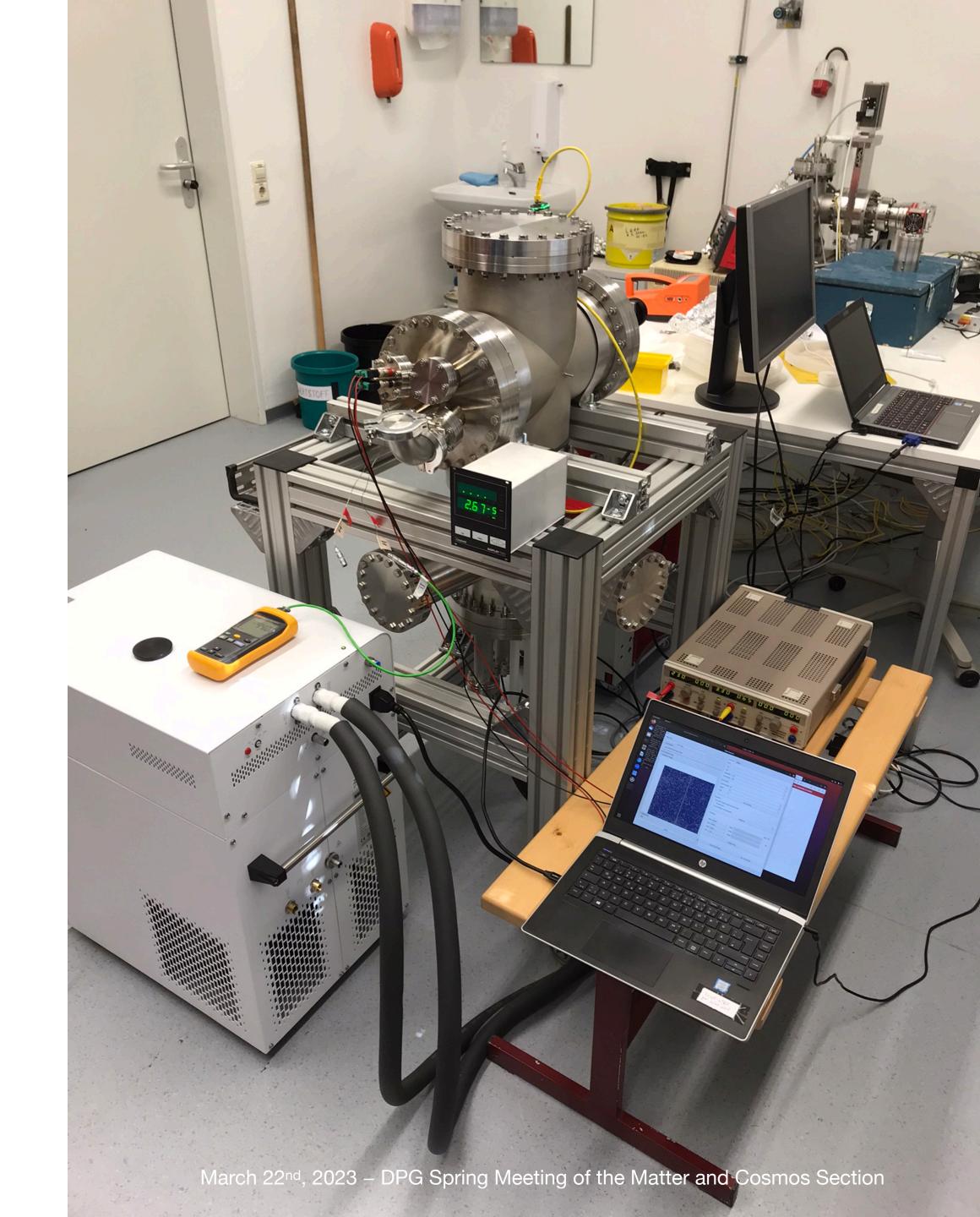
- LYSO: Lutetium-yttrium oxyorthosilicate crystal (Ce-doped) = anorganic scintillator
- naturally 2.6% <sup>176</sup>Lu ( $\rightarrow \beta^- + ^{176}Hf^* \rightarrow \gamma s$ ) = intrinsic scintillation





#### test setup low-noise SPAD operation

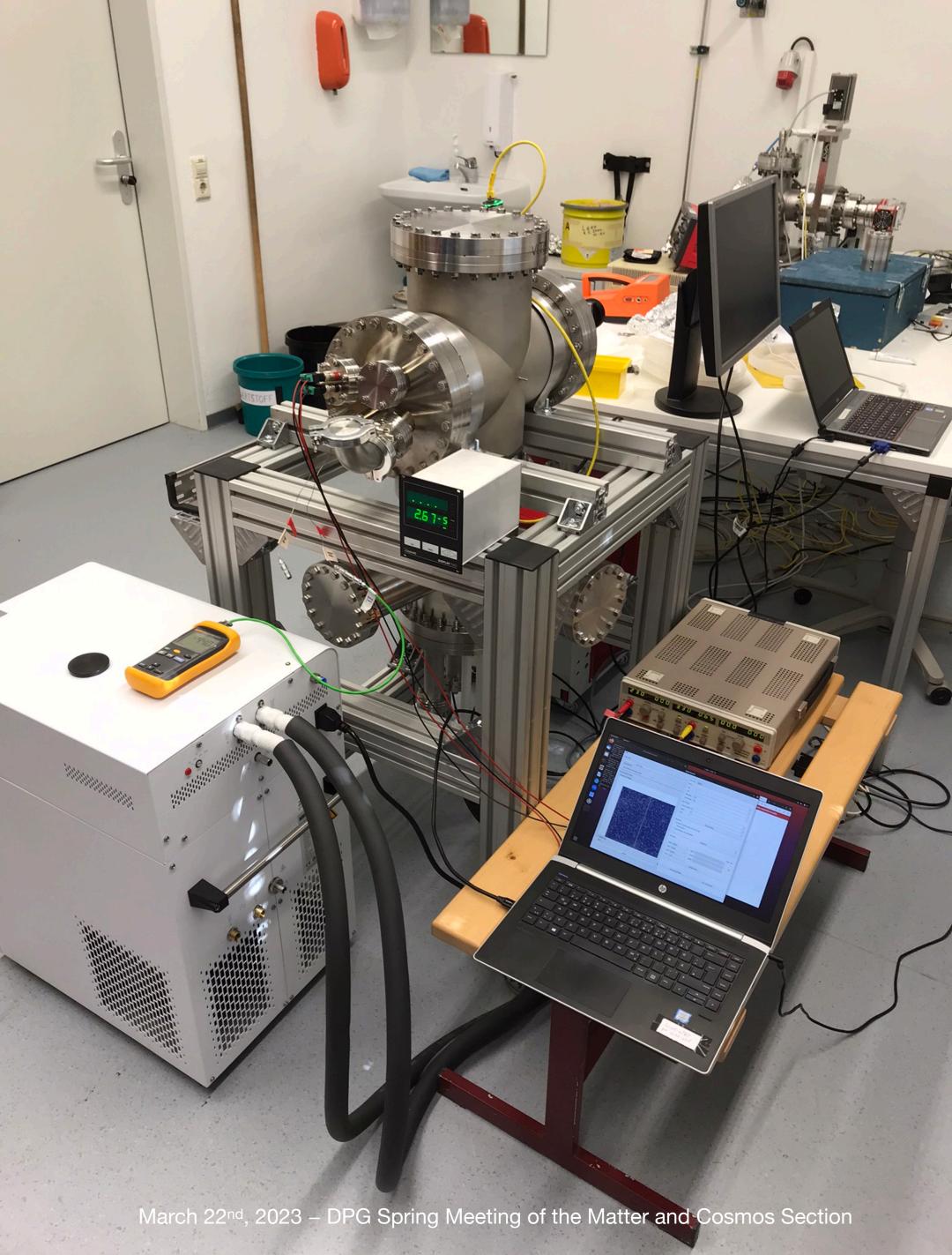
- coolable setup for measurements with the IDP4
- absolute darkness required
- USB and voltage access



Joscha Lauer (KIT-IAP)

#### test setup low-noise SPAD operation



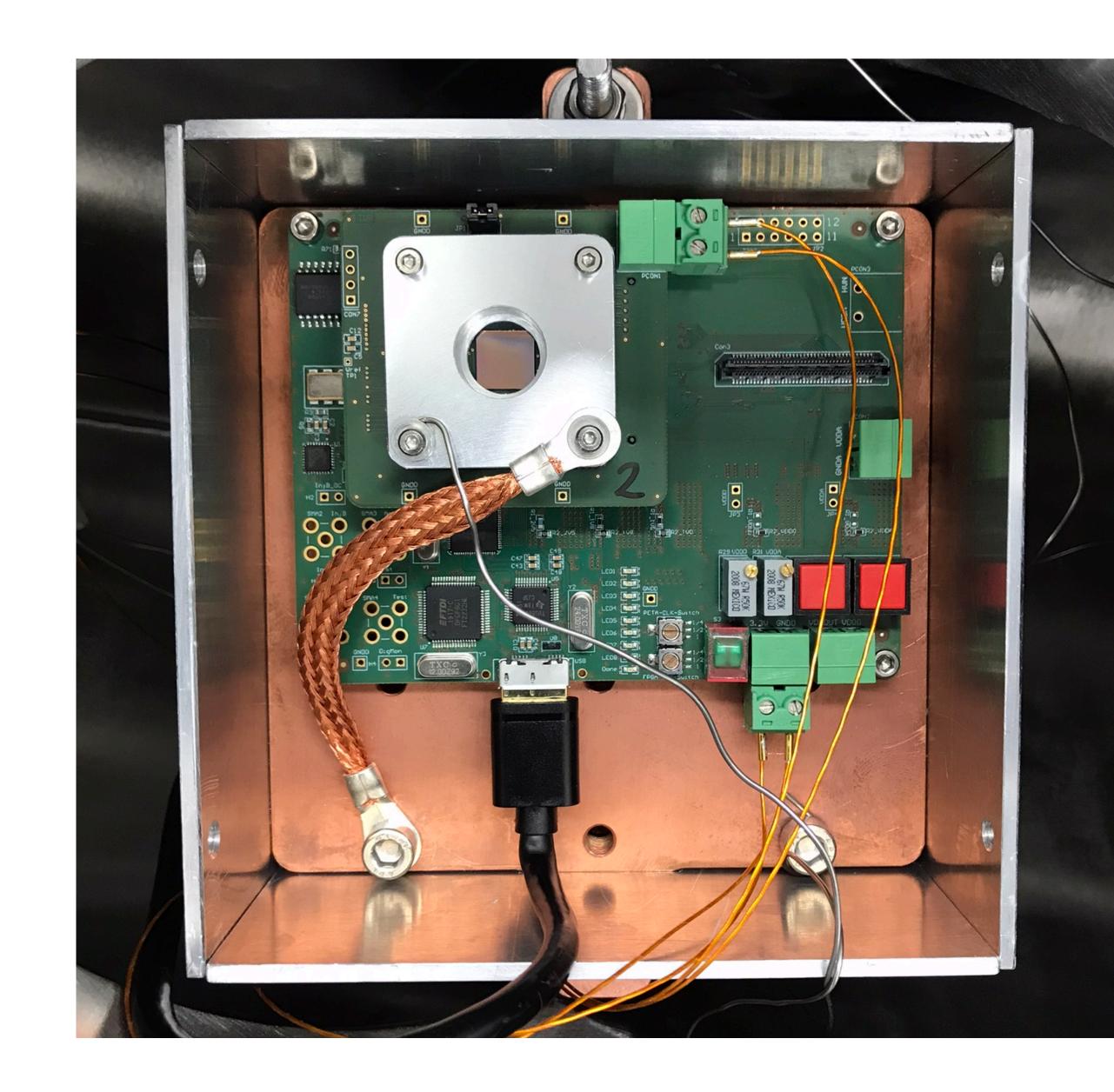


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12

#### test setup low-noise SPAD operation

- externally liquid-cooled copper block
- IDP4 PCB with cooling-coupled bulky cold aluminum cover
- cover temperature monitored (Pt100)
- temperatures down to approx. -50°C

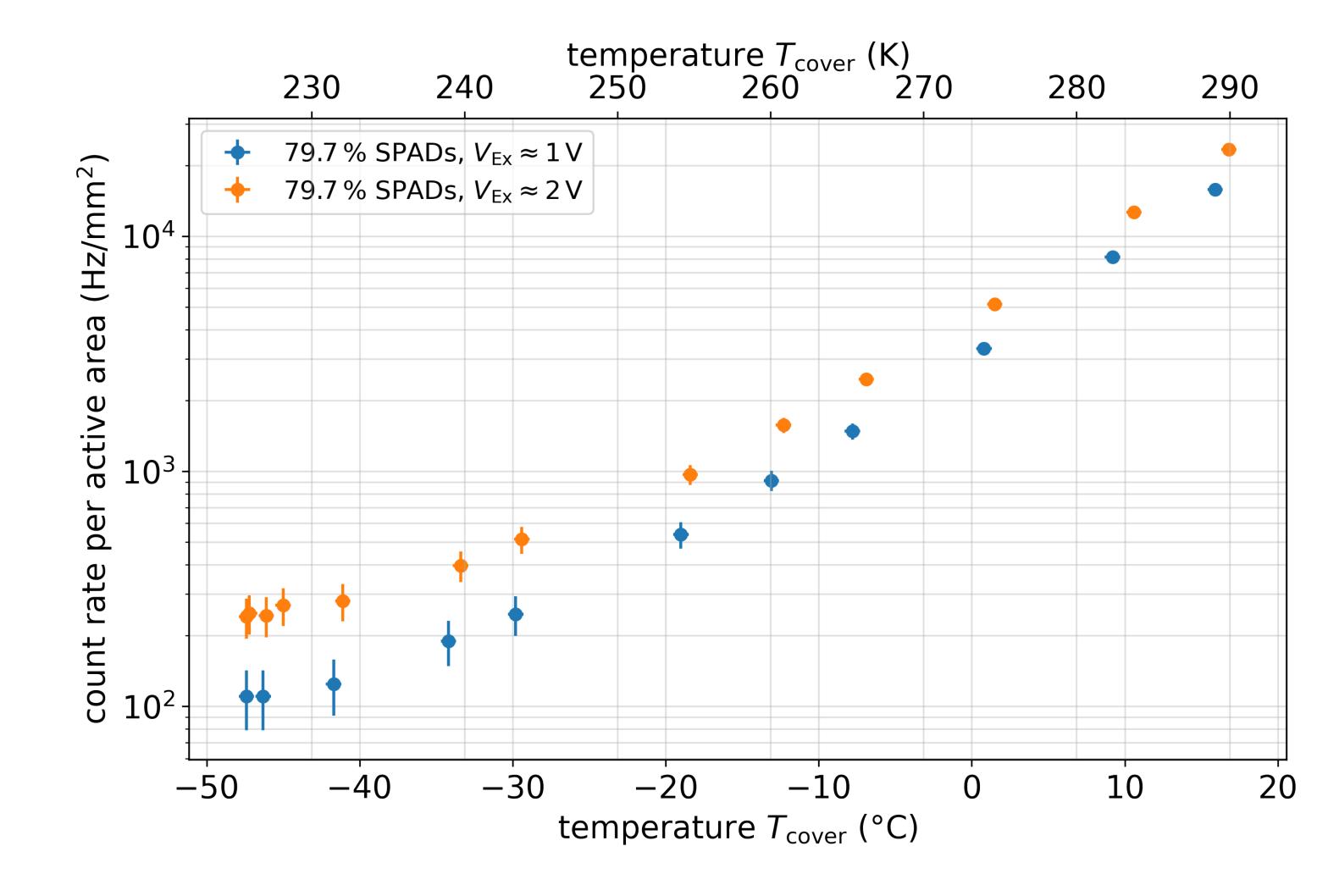


# SPAD noise measurement in setup

- hot SPADs are disengaged at RT
- bias voltage  $V_{\text{bias}}$  is adjusted at every temperature:

$$V_{\text{bias}} = V_{\text{BD}}(T) + V_{\text{Ex}}$$

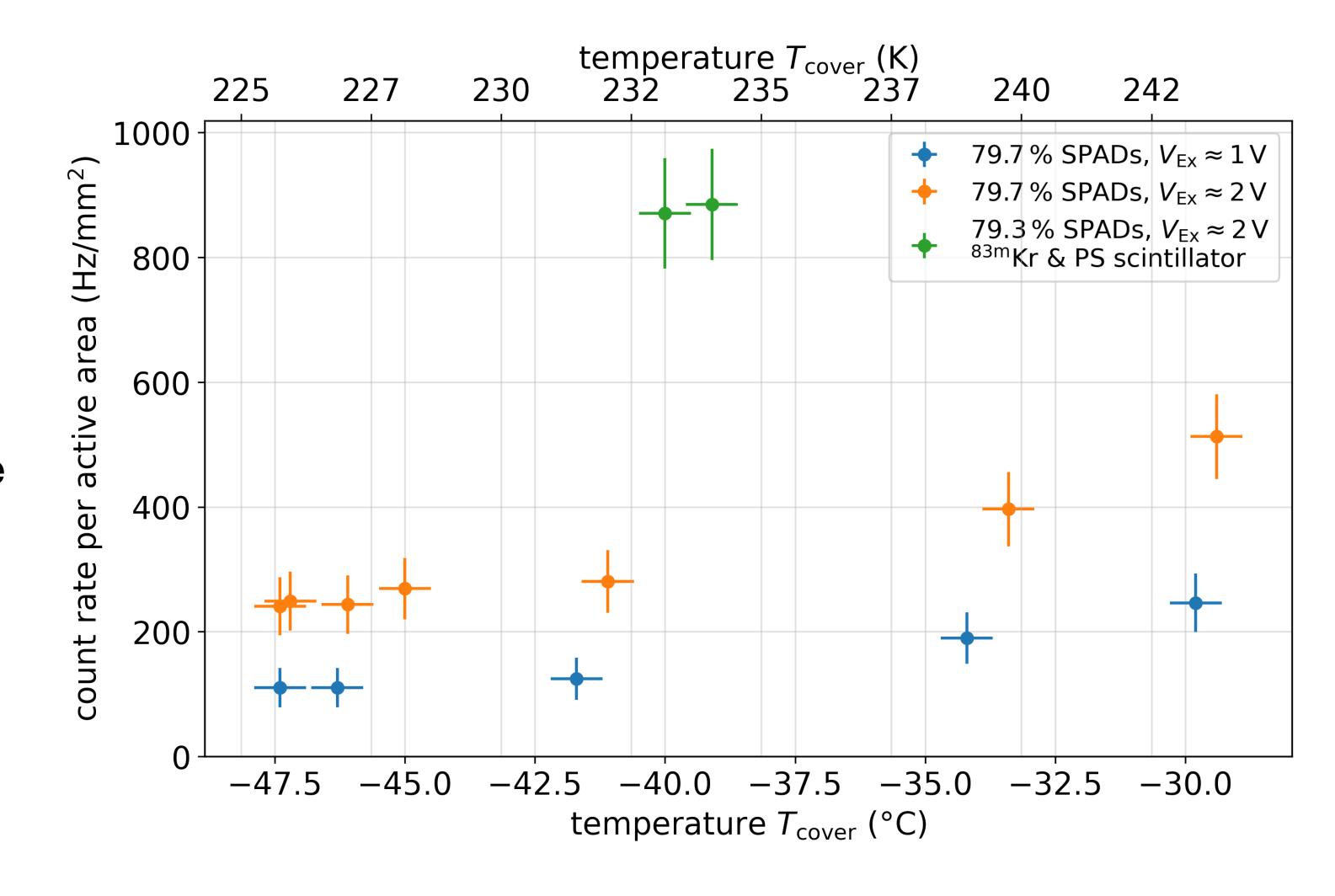
- excess voltage (GEIGER regime)  $V_{\text{Ex}} = \text{const.}$
- noise can be further reduced by triggering strategies (on event multiplicity)



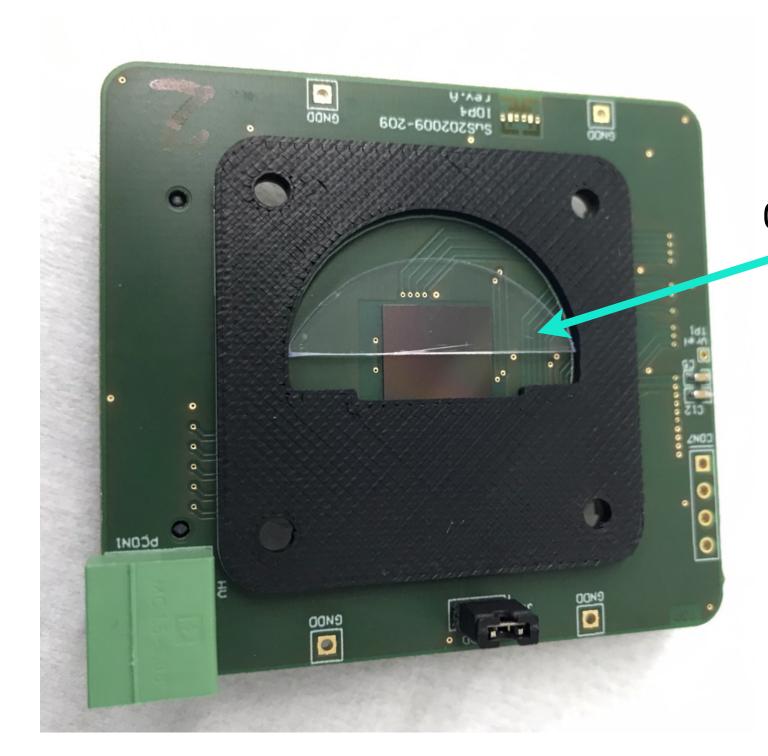
### first light

#### PS + 83mKr scintillation

- 0.5×7×8mm³ PS plastic scintillator plate (Epic Crystal)
- 1 mm above chip
- irradiation: ~0.55MBq 83mKr source
- 83mKr: O(10keV) electrons
- excess of roughly 600 Hz/mm<sup>2</sup>
- implications for scint-aTEF in terms of e.g. electron detection efficiency? → simulations

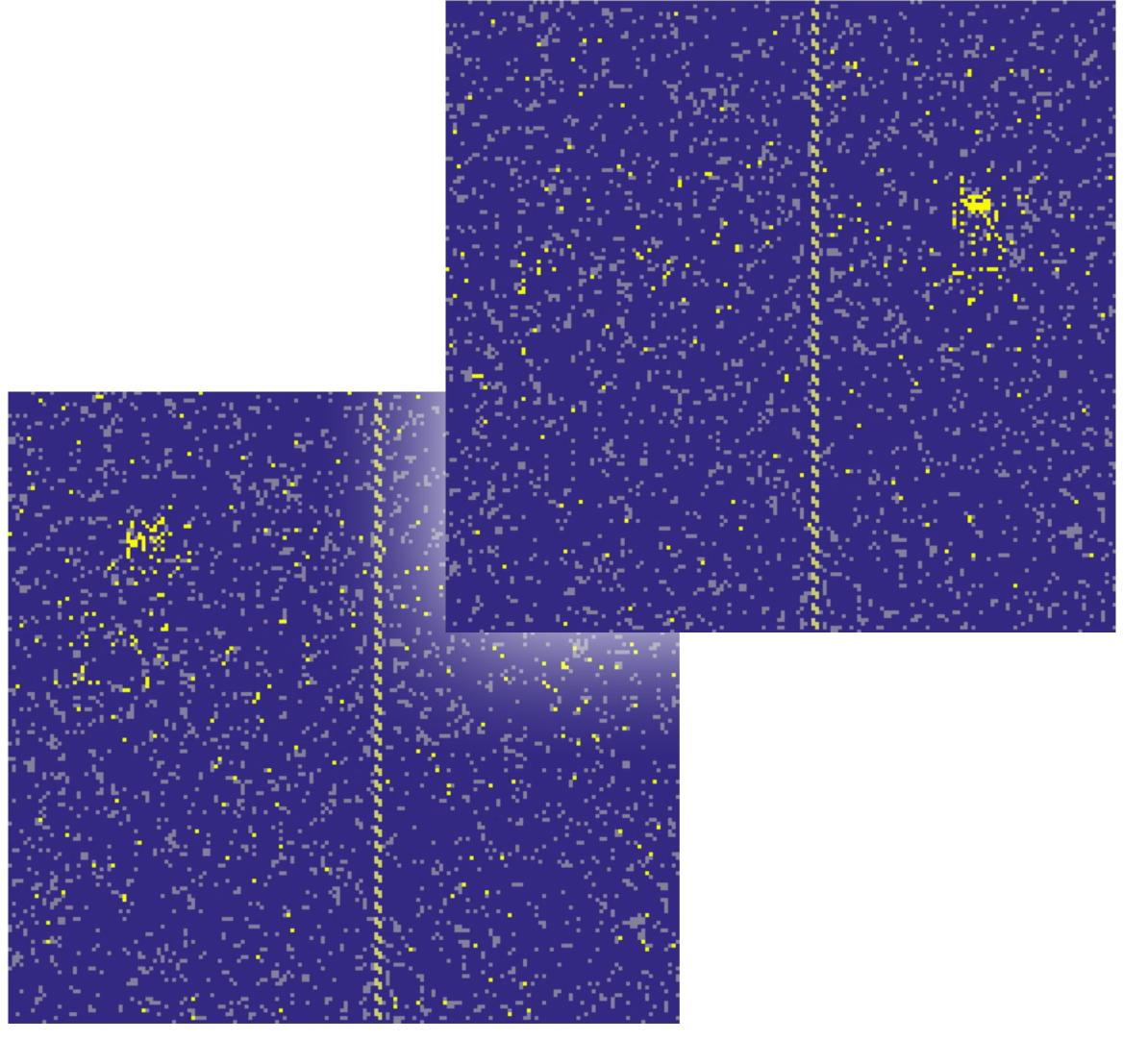


## PS + 83mKr: single scintillation events



0.5 mm thick PS plasticscintillator plate

- same measurement with direct contact (no gap) and partial IDP4 coverage
- single scintillation events resolved



# **summary & outlook** scintillating active Transverse Energy Filter (scint-aTEF)

- detector concept scint-aTEF: angle-dependent background discrimination in KATRIN-like setups
- scint-aTEF is a device for precise electron counting via scintillation
- digital SiPMs (CMOS-SPAD-based photosensor arrays): outstanding candidates for our purpose of single-photon detection and spatial event reconstruction
- first observation of thin plastic plate scintillation by keV electrons using the digital SiPM IDP4
- aim: investigation of single scintillation events and extension of corresponding simulation environment
- future: characterization of homemade scintillator samples and microstructures

### acknowledgements

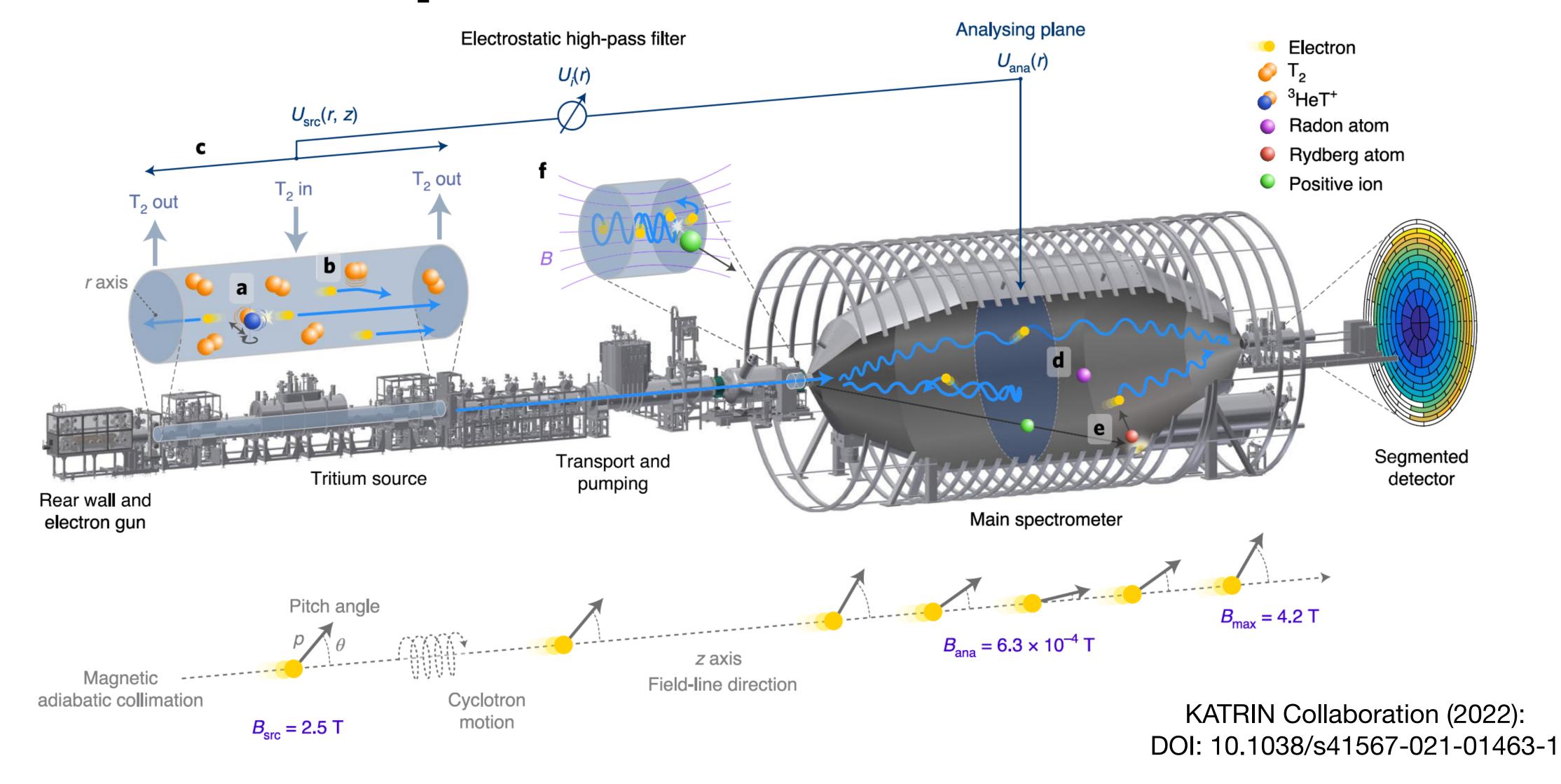
This work is supported by the Helmholtz Association, the Ministry for Education and Research BMBF (05A17PM3, 05A17PX3, 05A17VK2 and 05A17WO3), the Helmholtz Alliance for Astroparticle Physics (HAP) and the Helmholtz Initiative and Networking Fund (W2/W3-118).

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- 6. P. Fischer: ASICs for Photon Detection Integrating Avalanche Diodes and CMOS Readout. In 14th Terascale Detector Workshop 2022. Institute of Computer Engineering (ZITI), Heidelberg University. February 2022.
- 7. M. Ritzert: *Personal communication*. Institute of Computer Engineering (ZITI), Heidelberg University. February 2023.
- 8. M. Keller: Design and low temperature characterization of low noise single photon detector arrays for rare event search experiments with liquid noble gases. PhD thesis, Heidelberg University. July 2022.

## backup

## KATRIN setup



## magnetic adiabatic guiding in KATRIN

$$\theta(\vec{r}) = \arcsin\left(\sqrt{\frac{E(\vec{r}_0)}{E(\vec{r})}} \frac{|\vec{B}(\vec{r})|}{|\vec{B}(\vec{r}_0)|} \sin(\theta_0)\right)$$

$$\theta_{\text{max}} = \arcsin\left(\sqrt{\frac{B_{\text{S}}}{B_{\text{max}}}}\right) = 50.77^{\circ}$$

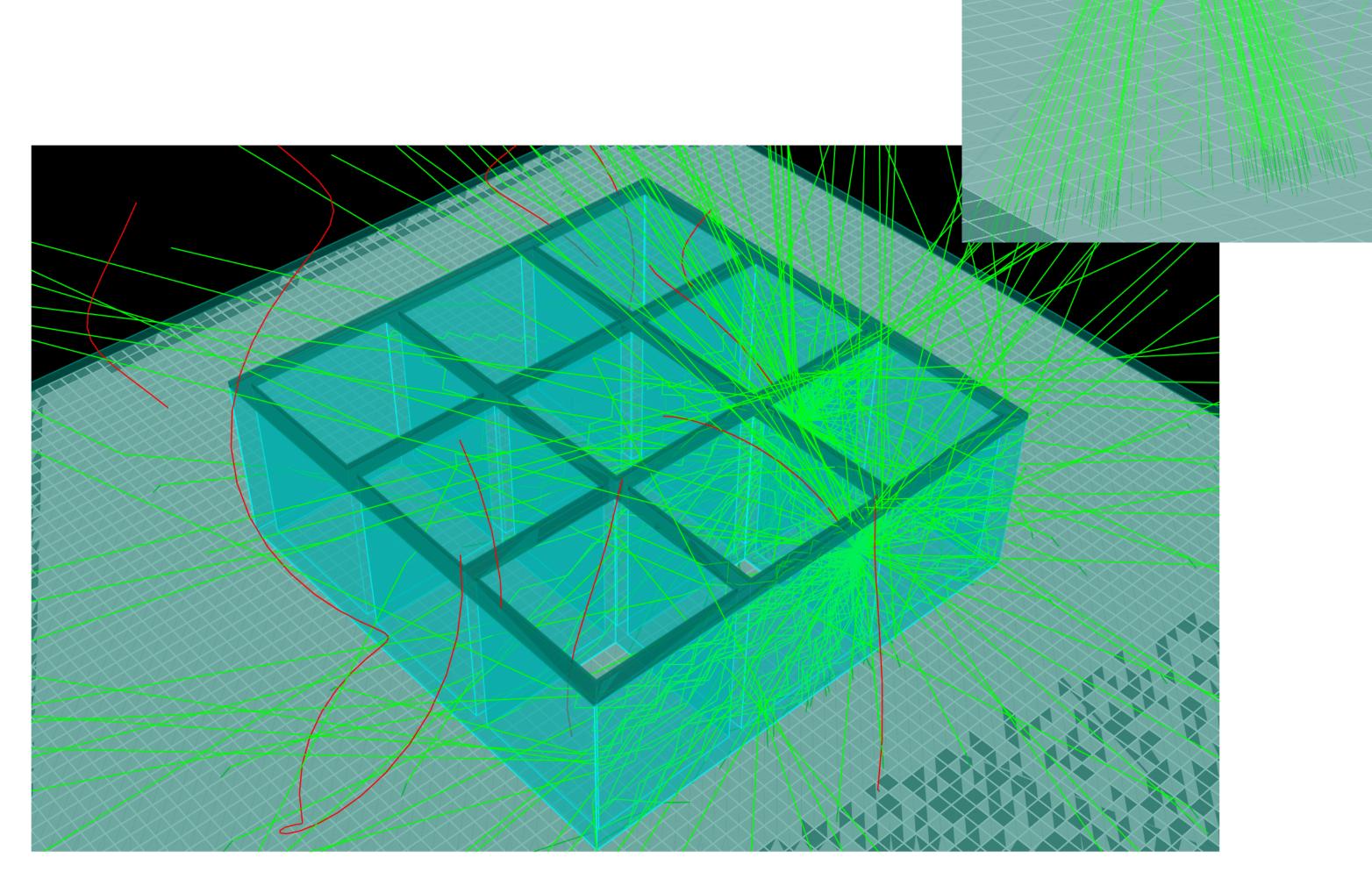
### electron cyclotron motion in KATRIN

$$r_g(\theta, B, U_0) = \frac{\gamma}{e} \sqrt{e|U_0|(e|U_0| + 2m_e)} \frac{\sin(\theta)}{B}$$

$$\ell_g(\theta, B, U_0) = 2\pi |U_0| \sqrt{1 + \frac{2m_e}{e|U_0|} \frac{\cos(\theta)}{B}}$$

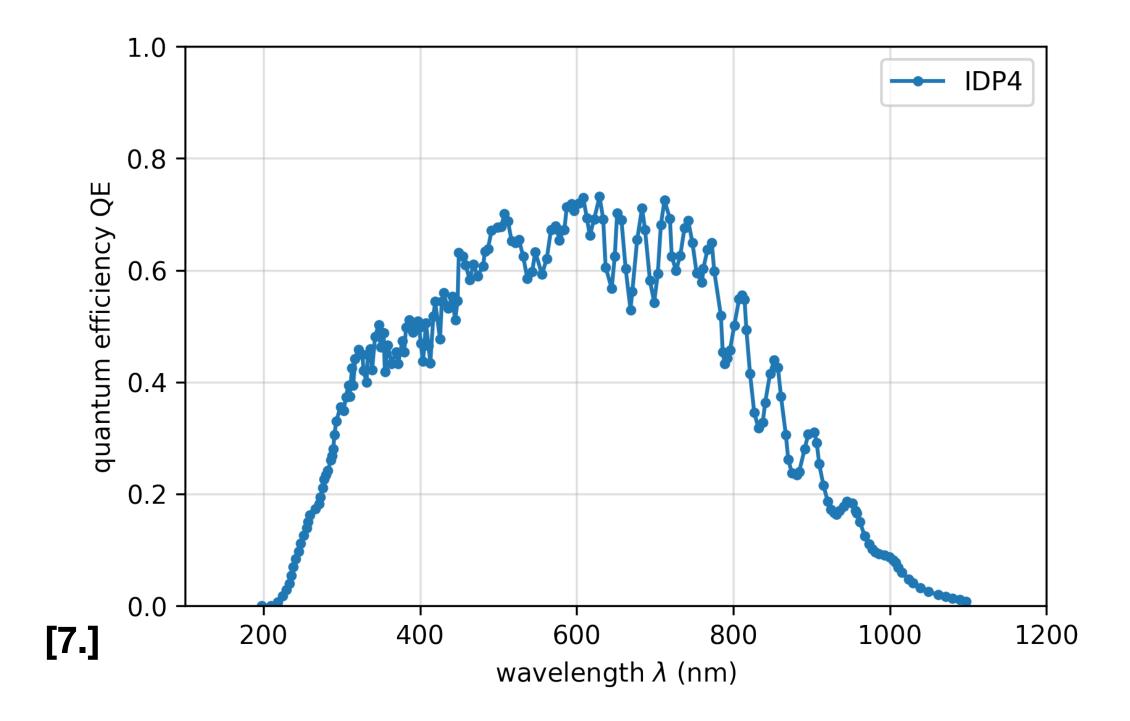
# scint-aTEF simulations Geant4 approach

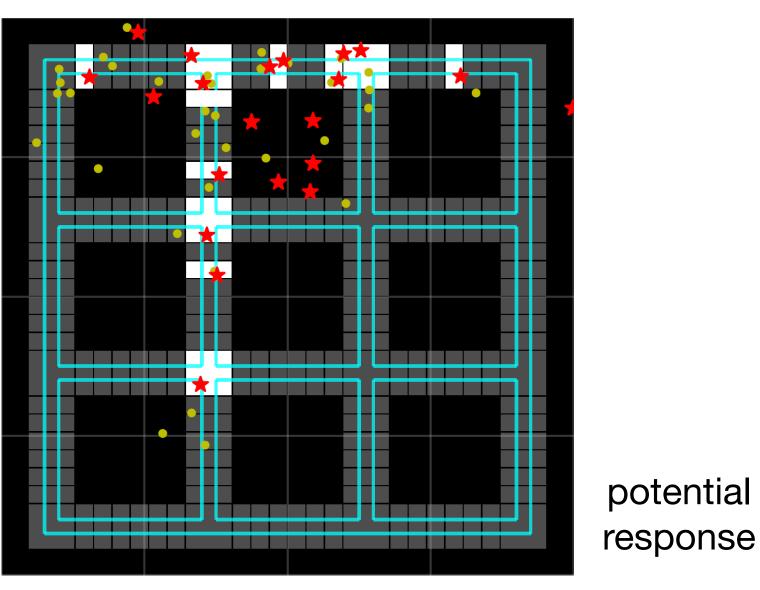
- included:
  - physics processes (scintillation, scattering,...)
  - optical properties (surface, reflection, attenuation,...)
  - homogen. B-field
- not included:
  - absorption & emission spectra
  - detailed electromagnetic environment



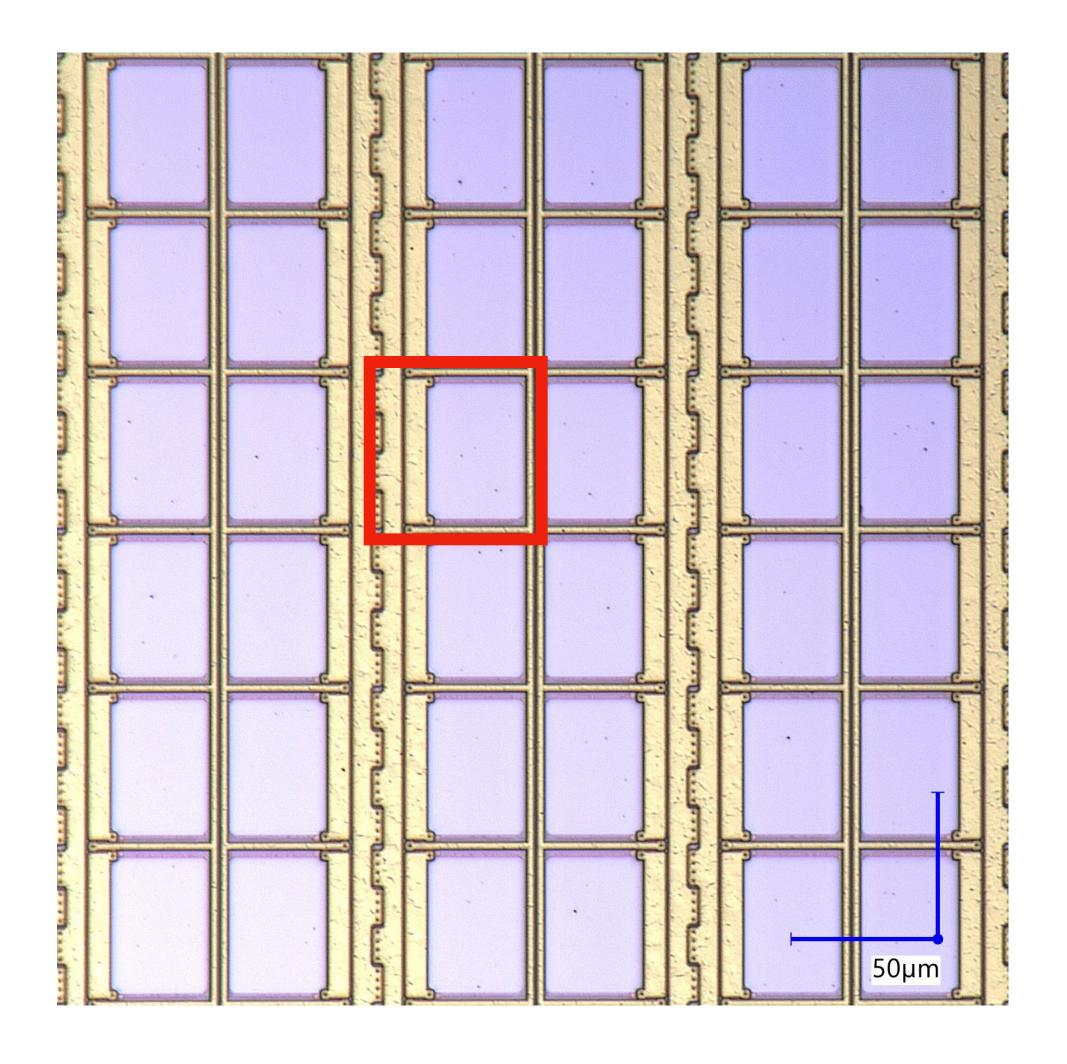
# scint-aTEF simulations setup performance & optimization

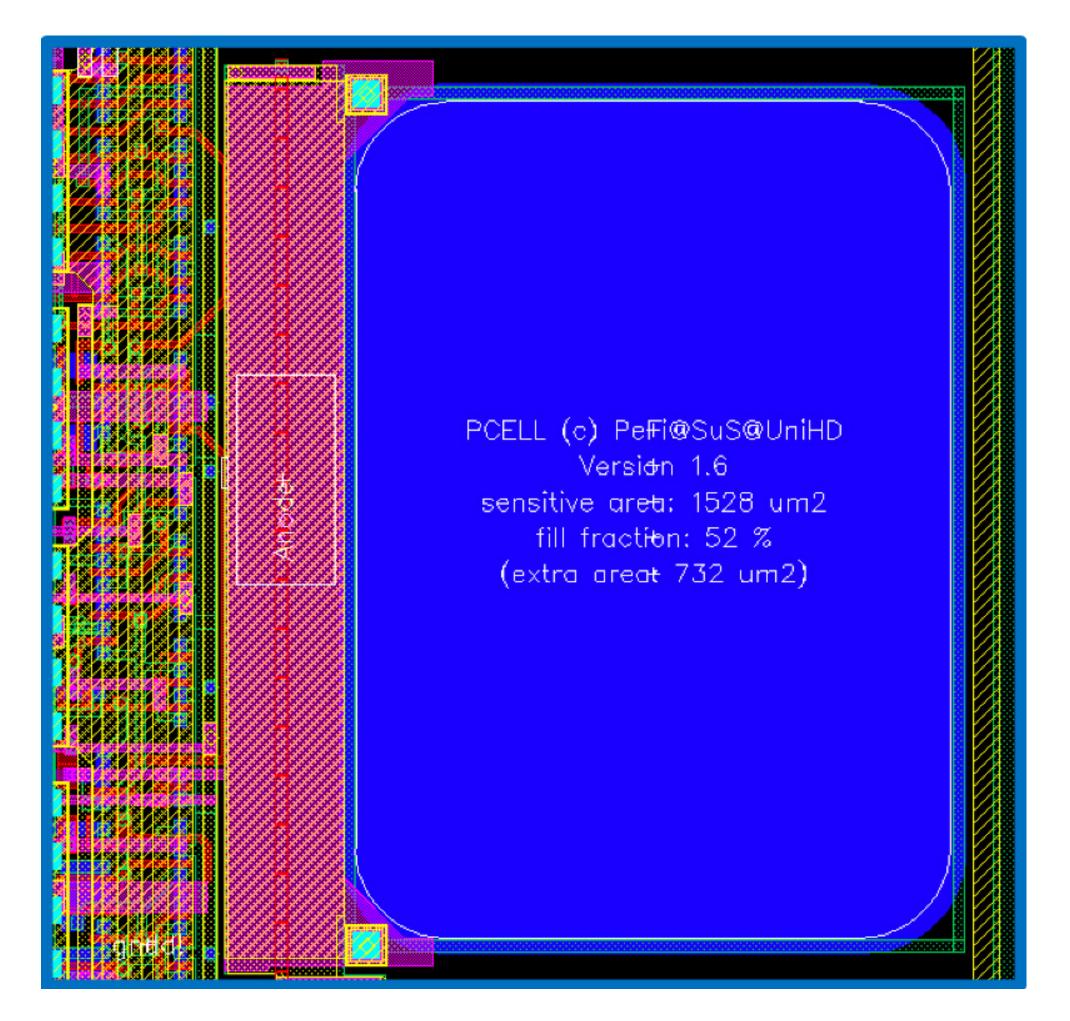
- PDE =  $\varepsilon_{\text{coll}} \cdot \varepsilon_{\text{geom}} \cdot \text{QE} \cdot \varepsilon_{\text{trig}}$
- results:
  - ~50–60% guiding/collection efficiency  $\varepsilon_{coll}$  for scintillation light (with stated parameters, s. 4)
  - >10 detected γs/signature
- optimization of β detection and signal-to-background ratio
- investigation of different trigger strategies to discriminate remaining noise





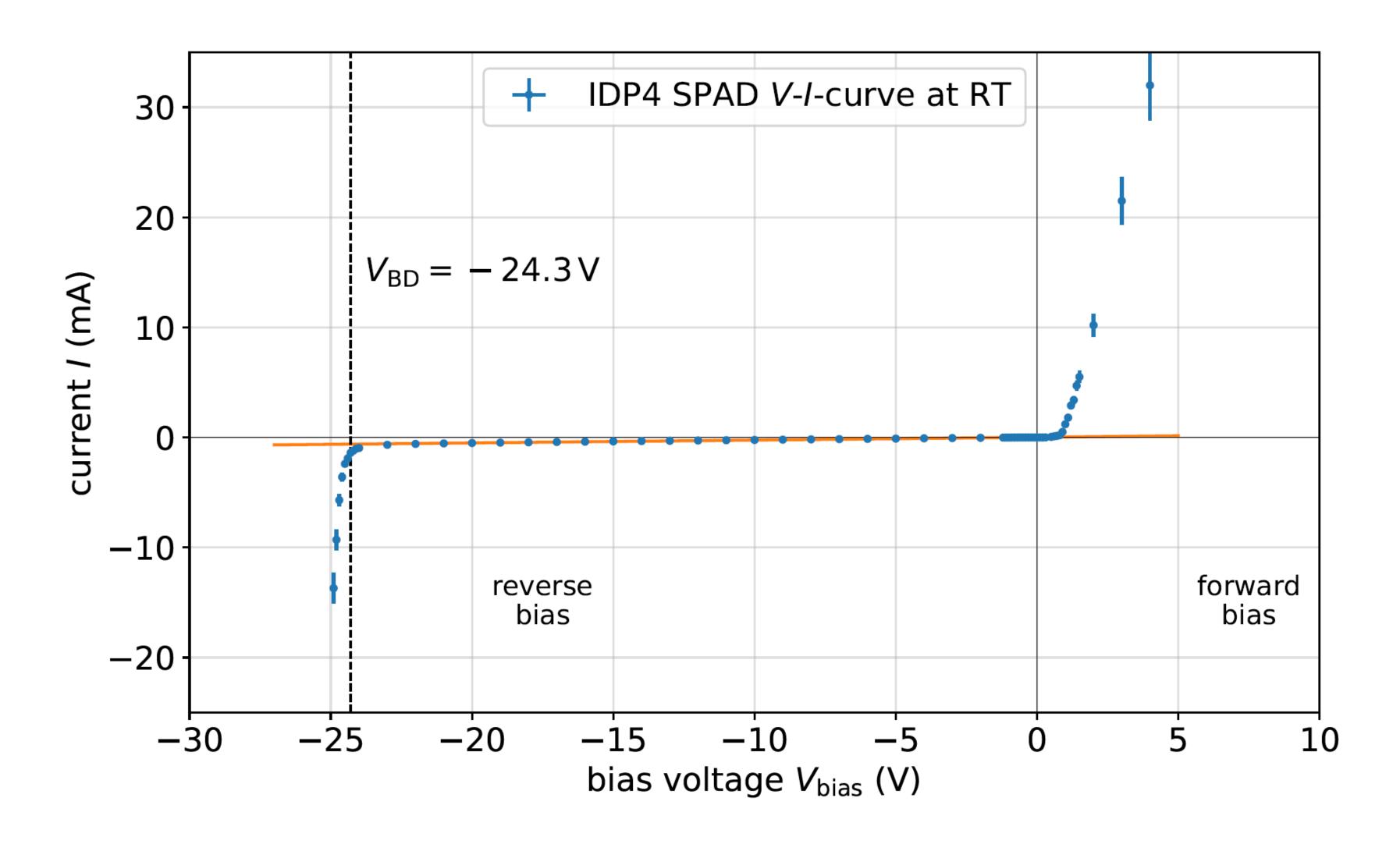
### SPAD layout on the IDP4





[6.]

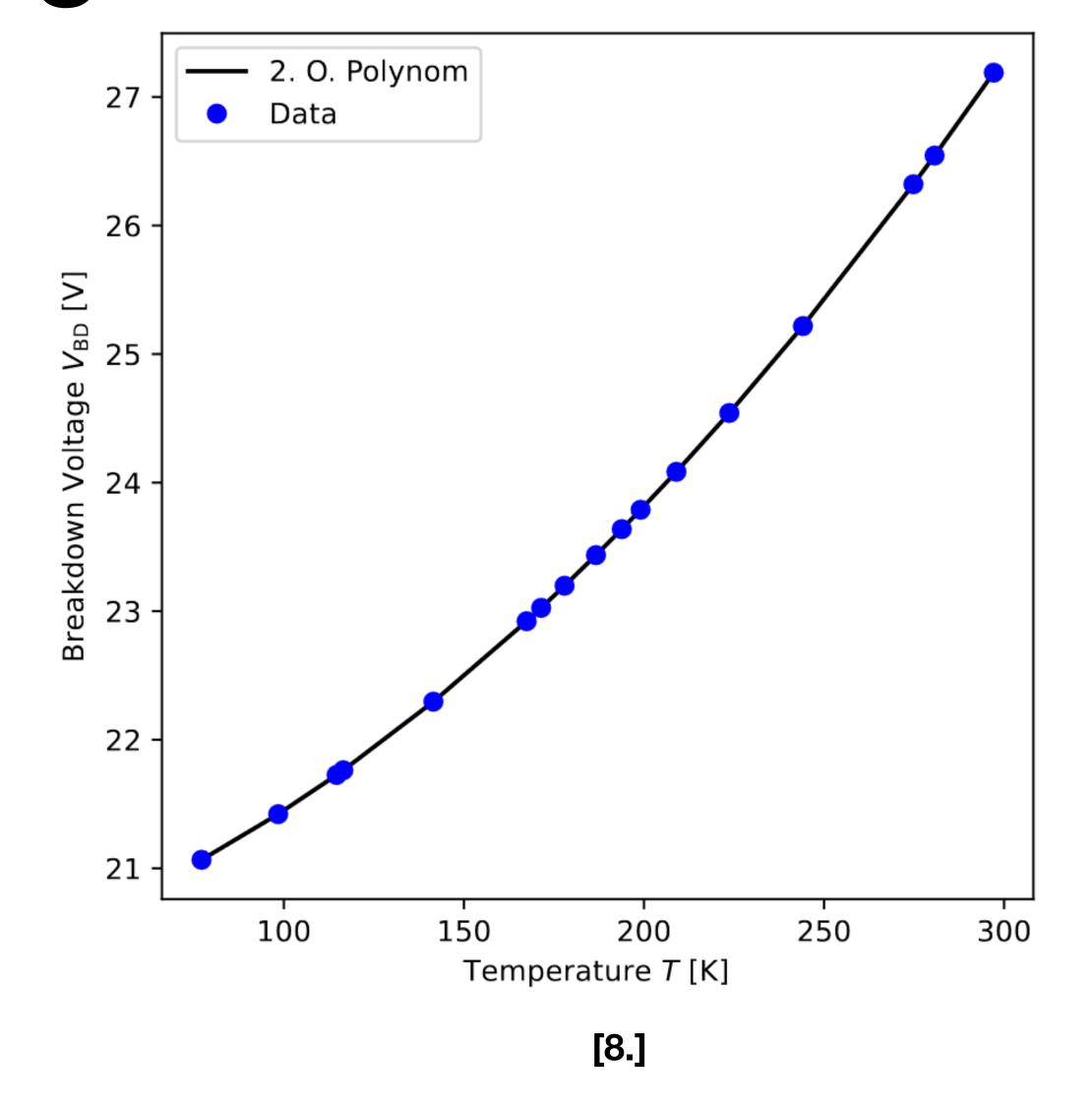
## SPAD V-/-curve (IDP4)



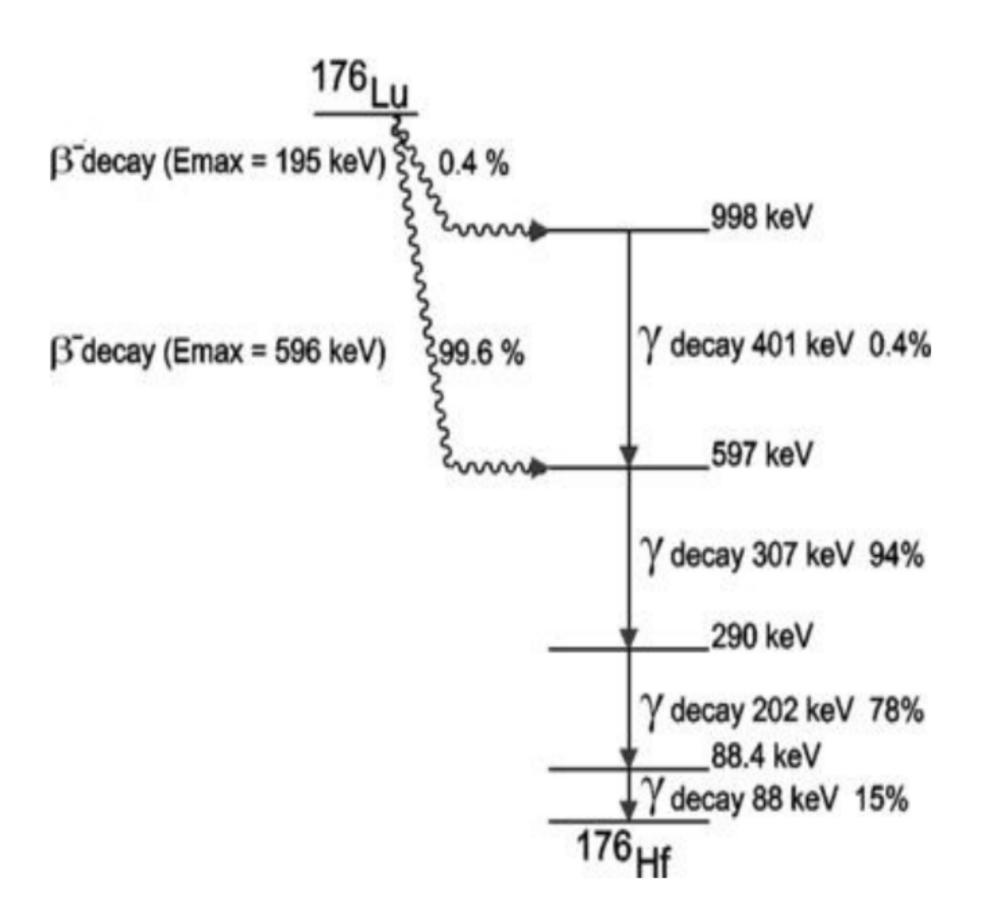
### SPAD breakdown voltage

temperature dependence

- temperature dependence of IDP2 SPAD breakdown voltage  $V_{\rm BD}$
- IDP2: predecessor of IDP4 with different absolute values



### LYSO: 176Lu decay scheme



T. Kaltsas *et al.* (2015): DOI: 10.1109/NSSMIC.2015.7582211

### 83mKr: 83Rb decay scheme

